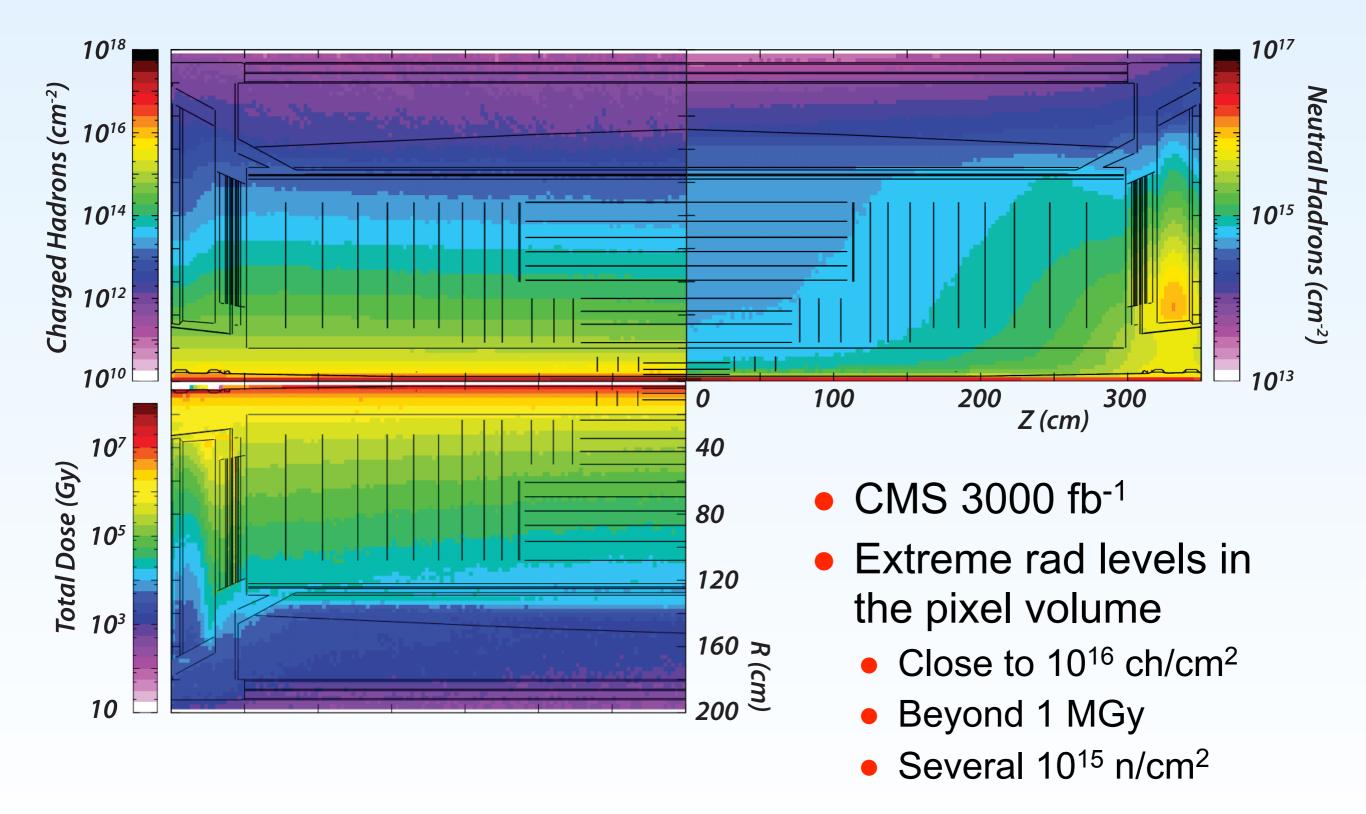
Optical link prospects for Phase II Pixels

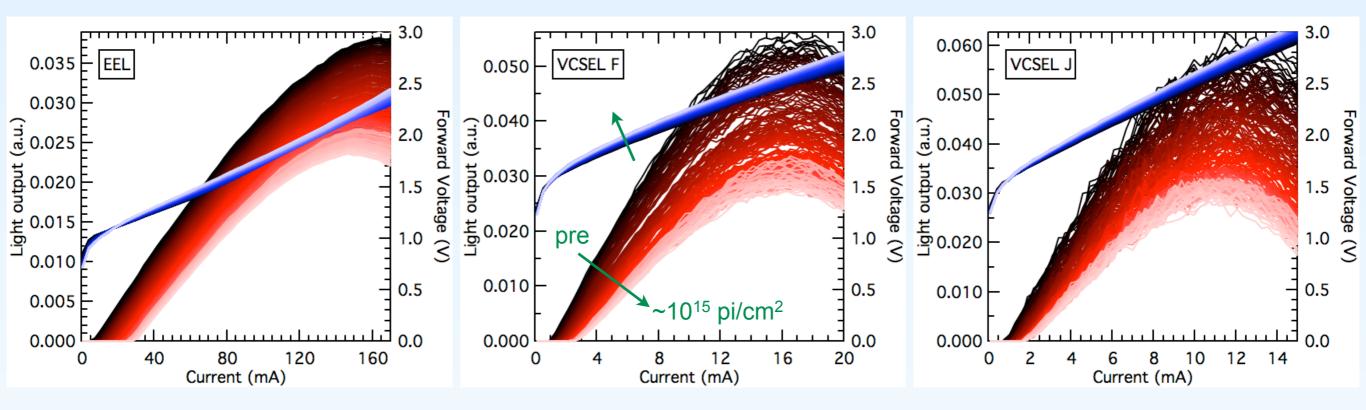
- CERN
- Some remarks on the possibilities of using Optical Links in the innermost regions of CMS after LS3
- Radiation effects
- Power dissipation
- Size

Radiation levels



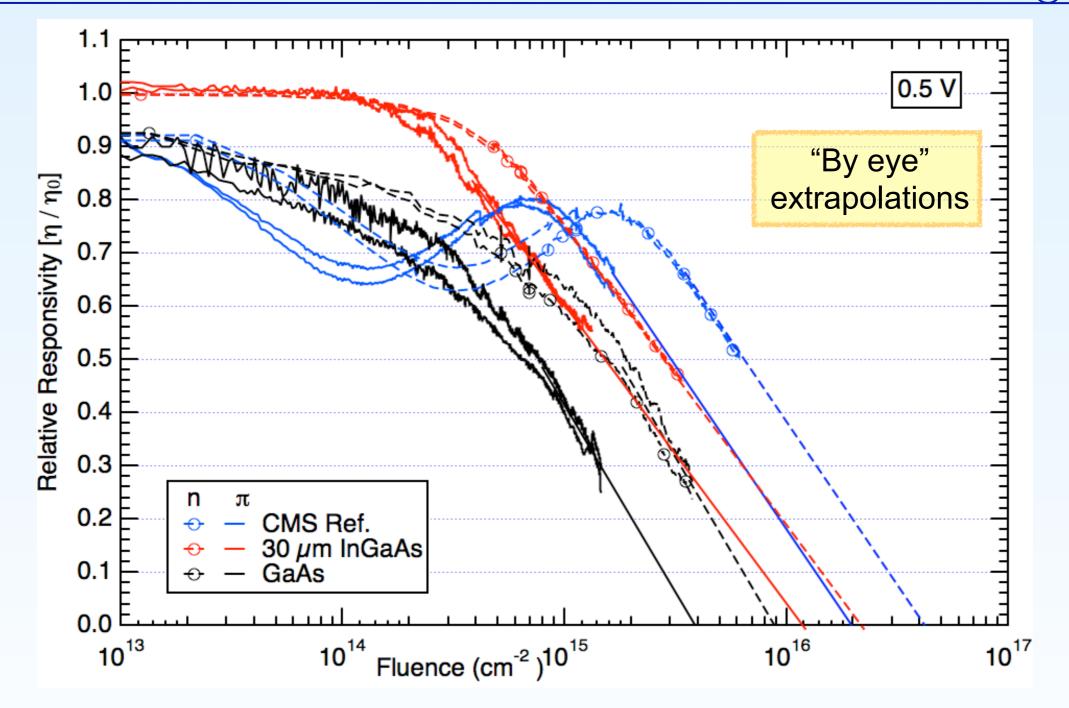
ER





- By eye, might assume lasers could survive "a few" 10¹⁵ /cm²
 - Need to be able to track threshold changes
 - Deal with output amplitude degradation in link budget
- Annealing helps a bit
 - Gain a factor of two in reduction of damage at SLHC fluxes

Impact of PD Responsivity loss

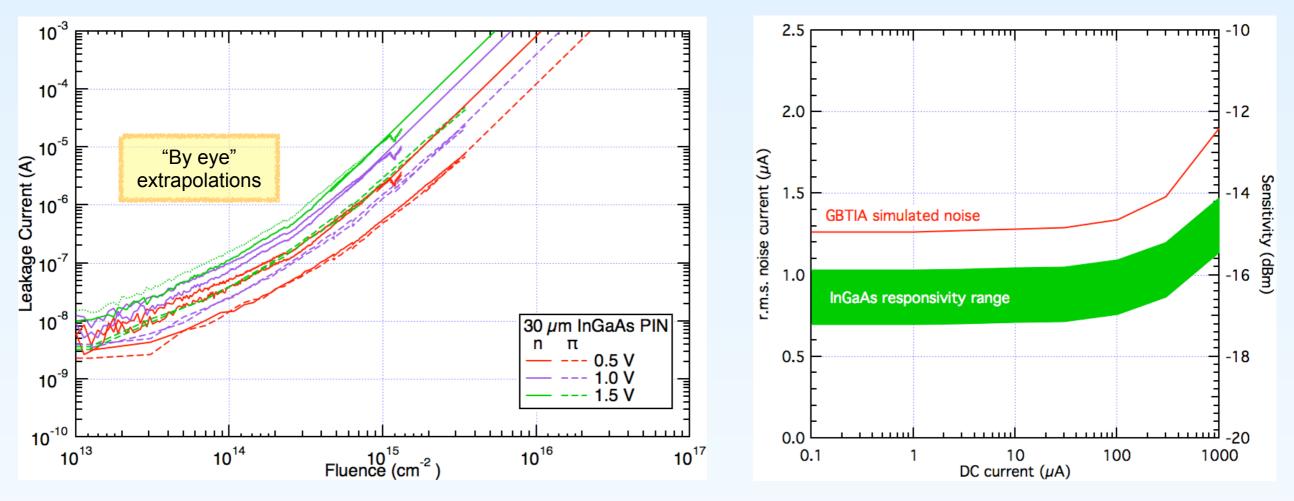


GaAs non-functional after around 4x10¹⁵ pi/cm²

InGaAs non-functional after around 10¹⁶ pi/cm²

No annealing CMS Phase 2 Pixel Electronics – 20 Nov. 2013

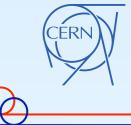
Impact of PD Leakage Current



Reminder: no leakage in GaAs devices

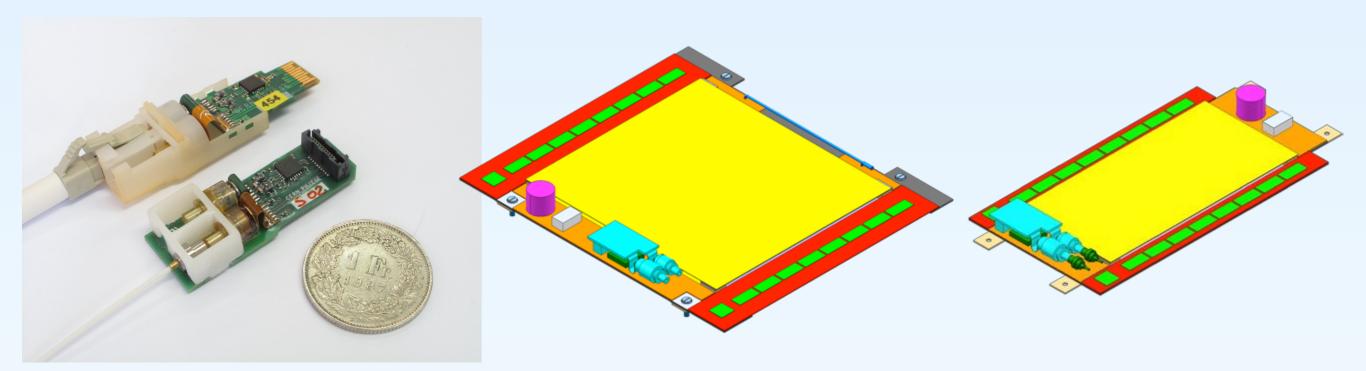
- 1 mA leakage current adds 1.7 dB sensitivity penalty
- Not clear that removal of DC-current is possible beyond this?

Power Dissipation



Current Versatile Link modules (5 Gb/s)

- Tx draws approx. 100 mA from 2.5 V Call it 400 mW per TRx
- Rx draws approx. 50 mA from 2.5 V
- Prospect of reducing this by factor of 2 seems do-able
 - Need to work much harder on ASIC and finding a lower-power component to find further factors of reduction
 - To be checked with further iterations of laser driver ASICs



- Could perhaps fit components packaged in industry std. size packages for Tracker 2S (and PS) modules
- Further size reduction requires custom packaging effort
 - To be pursued within VL+ follow-up project
- Only cost-effective with volume



Discussion

- Are there new technologies out there that promise to be significantly more rad hard, smaller and lower power?
- Do we have to push the opto-electronics out of the innermost regions?
- Other mitigation strategies?